**PWM Control 1.5A Step-Down Converter** 

# **FEATURES**

- Wide Input Voltage Range: 7V to 30V
- LED Output Current Up to 1.5A
- Soft-start
- Single pin on/off and brightness control using DC voltage or PWM
- High efficiency (up to 97%)
- Up to 1MHz switching frequency
- Typical 5% output current accuracy
- SOT-23 and SOP-8 Lead-free Package

### **Applications**

- LED/Display Back Light Driver
- Lightings
- Portable Communication Devices
- Handheld Electronics

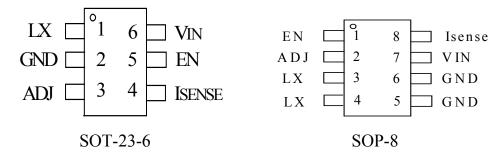
### **GENERAL DESCRIPTION**

The T6322A is a continuous mode inductive step-down converter, designed for driving single or multiple series connected LEDs efficiently from a voltage source higher than the LED voltage. The device operates from an input supply between 7V and 30V and provides an externally adjustable output current of up to 1.5A. Depending upon supply voltage and external components, this can provide up to 42 watts of output power. The T6322A includes the output switch and a highside output current sensing circuit, which uses an external resistor to set the nominal average output current. Output current can be adjusted above, or below the set value, by applying an external control signal to the 'ADJ' pin. The ADJ pin will accept either a DC voltage or a PWM waveform. Depending upon the control frequency, this will provide either a continuous or a gated output current. The PWM filter components are contained within the chip. The T6322A is available in SOT-23 and SOP-8 Lead-free package.

## PART NUMBER EXAMPLES

PART NO.	PACKAGE
T6322A-AXG	SOT-23
T6322A-ADG	SOP-8

# PIN ARRANGEMENT(Top view)



### **PIN DESCRIPTION**

SYMBOL	SOT-23	SOP-8	DESCRIPTION	
LX	1	3,4	brain of NDMOS switch	
GND	2	5,6	Ground	
ADJ	3	2	<ul> <li>Multi-function On/Off and brightness control pin:</li> <li>Leave floating for normal operation.(VADJ = VREF = 1.25V giving nominal average output current IOUTnom = 0.1/RS)</li> <li>Drive with DC voltage (0V &lt; VADJ &lt; 2.5V) to adjust output current from 0% to 200% of IOUTnom</li> <li>Drive with PWM signal from open-collector or open-drain transistor, to adjust output current. Adjustment range 0% to 100% of IOUTnom for f &gt;10kHz and 0% to 100% of IOUTnom for f &lt; 500Hz</li> </ul>	
Isense	4	8 Connect resistor Rs from this pin to VIN to define nominal avera output current IOUTnom = $0.1/Rs$		
EN	5	1	Enable control signal, H: Ative, L : Power Down	
VIN	6	7	Input voltage (7V to 30V). Decouple to ground with 10uF or higher X7R ceramic capacitor close to device	

# **ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit	
Voltage on intput pin relative to GND	VIN	-0.3 to +36	V	
Isense pin Voltage		-5 to +0.3	V	
ADJ and EN pin Voltage		-0.3 to +6	V	
Operating Temperature Rang	TA	-40 to +125	°C	
Maximum Soldering Temperature (at leads, 10 sec)	T <sub>LEAD</sub>	300	°C	
Storage Temperature Rang	Т <sub>S</sub>	-65 to +150	°C	
Power Dissipation, PD $(a)$ TA = 25°C	SOT-23	0.35	W	
i ower Dissipation, i D @ IA - 25 C	SOP-8	0.8	**	
Package Thermal Resistance, $\theta JA$	SOT-23	250	°C/W	
	SOP-8	178	C/ W	

#### **Electrical Characteristics**

 $(TA = -40 \text{ to } 85^{\circ}\text{C} \text{ unless otherwise noted. Typical values are at TA = 25^{\circ}\text{C}, VDD = 12V)$ 

Symbol	Description	Conditions	Min.	Тур.	Max	Unit
VIN	Input Voltage		7	-	30	V
Viru	Internal regulator start-up threshold	VIN rising		5.65		V
Vird	Internal regulator shutdown	VIN falling		5.55		V
Iqoff	Quiescent supply current with output off	EN pin grounded		35		uA
Iqon	Quiescent supply current with output switching	ADJ pin floating f = 250kHz		1.8	5.0	mA
VSENSE	Mean current sense threshold Voltage (Defines LED current setting accuracy)	Measured on ISENSE pin with respect to $V_{IN}$ , $V_{ADJ} = 1.25V$	95	100	105	mV
VSENTH	Sense threshold hysteresis			±15		%
Isense	ISENSE pin input current	$V_{SENSE} = V_{IN} - 0.1$		10		uA
VREF	Internal reference voltage	Measured on ADJ pin with pin floating		1.25		V
$\Delta V_{REF} / \Delta T$	Temperature coefficient of VREF			50		ppm/K
VADJ	External control voltage range on ADJ pin for DC brightness control*		0		2.5	V
VIHEN	EN Input Voltage Hight		2			V
VILEN	EN Input Voltage Low				0.8	V
Radj	Resistance between ADJ pin and VREF	0< VADJ < 2.5V		200		Kohm
Ilxm	Continuous LX switch current				1.5	А
RLX	LX Switch 'On' resistance	@ ILX = 1.5 A		0.3	0.45	ohm
Ilxi	LX switch leakage current				5	uA
T <sub>TP</sub>	Thermal Shutdown Protect			160		°C

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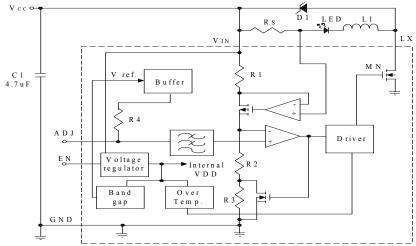
Electric	al Characteristics (continuous	)				
	Duty cycle range of PWM signal applied to ADJ pin during low frequency PWM dimming mode PWM frequency<500Hz PWM amplitude = VREF Measured on ADJ pin		0.01		1	
	Brightness control range			100:1		
Dpwmh	Duty cycle range of PWM signal applied to ADJ pin during high frequency PWM dimming mode	PWM frequency>10KHz PWM amplitude = VREF Measured on ADJ pin			1	
	Brightness control range			5:1		
fLX	Operating frequency	ADJ pin floating, L = 33uH (0.093 ohm) IOUT=1A @VLED = 3.6V Driving 1 LED		280		KHz
TONmin	Minimum switch 'ON' time	LX switch 'ON'		240**		ns
TOFFmin	Minimum switch 'OFF' time	LX switch 'OFF'		200**		ns
TONminR	Recommended minimum switch 'ON' time	LX switch 'ON'		800		ns
fLXmax	Recommended maximum operating frequency				1	MHz
DLX	Recommended duty cycle range of output switch at fLXmax		0.3		0.7	
Tpd	Internal comparator propagation delay			50		ns

Notes :

\*100% brightness corresponds to VADJ = VADJ(nom) = VREF. Driving the ADJ pin above VREF will increase the VSENSE. threshold and output current proportionally.

\*\*Parameters are not tested at production. Parameters are guaranteed by design, characterization and process control.

### **Block Diagram**



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### **Functional Description**

The device, in conjunction with the coil (L1) and current sense resistor (RS), forms a selfoscillating continuous-mode buck converter.

### **Device** operation

Operation can be best understood by assuming that the ADJ pin of the device is unconnected and the voltage on this pin (VADJ) appears directly at the (+) input of the comparator.

When input voltage VIN is first applied, the initial current in L1 and RS is zero and there is no output from the current sense circuit. Under this condition, the (-) input to the comparator is at ground and its output is high. This turns MN on and switches the LX pin low, causing current to flow from VIN to ground, via RS, L1 and the LED(s). The current rises at a rate determined by VIN and L1 to produce a voltage ramp (VSENSE) across RS. The supply referred voltage VSENSE is forced across internal resistor R1 by the current sense circuit and produces a proportional current in internal resistors R2 and R3. This produces a ground referred rising voltage at the (-) input of the comparator. When this reaches the threshold voltage (VADJ), the comparator output switches low and MN turns off. The comparator output also drives another NMOS switch, which bypasses internal resistor R3 to provide a controlled amount of hysteresis. The hysteresis is set by R3 to be nominally 15% of VADJ.

When MN is off, the current in L1 continues to flow via D1 and the LED(s) back to VIN. The current decays at a rate determined by the LED(s) and diode forward voltages to produce a falling voltage at the input of the comparator. When this voltage returns to VADJ, the comparator output switches high again. This cycle of events repeats, with the comparator input ramping between limits of VADJ  $\pm$  15%.

### Switching thresholds

With VADJ = VREF, the ratios of R1, R2 and R3 define an average VSENSE switching threshold of 100mV (measured on the ISENSE pin with respect to VIN). The average output current IOUTnom is then defined by this voltage and RS according to:

IOUTnom = 100mV/RSNominal ripple current is  $\pm 15 \text{mV/Rs}$ 

### Adjusting output current

The device contains a low pass filter between the ADJ pin and the threshold comparator and an internal current limiting resistor (200kohn nom) between ADJ and the internal reference voltage. This allows the ADJ pin to be overdriven with either DC or pulse signals to change the VSENSE switching threshold and adjust the output current. The filter is third order, comprising three sections, each with a cut-off frequency of nominally 4kHz. Details of the different modes of adjusting output current are given in the applications section.

### **Output shutdown**

The output of the low pass filter drives the shutdown circuit. When the input voltage to this circuit falls below the threshold, the internal regulator and the output switch are turned off. The voltage reference remains powered during shutdown to provide the bias current for the shutdown circuit. Quiescent supply current during shutdown is nominally 35uA and switch leakage is below 5uA.

### **Applications Information**

#### Setting nominal average output current with external resistor RS

The nominal average output current in the LED(s) is determined by the value of the external current sense resistor (RS) connected between VIN and ISENSE and is given by:

IOUTnom = 0.1/Rs [for RS  $\ge 0.066$  ohm]

The table below gives values of nominal average output current for several preferred values of current setting resistor (RS) in the typical application circuit :

RS (ohm)	0.066	0.1	0.142	0.285
Nominal average	1500	1000	700	350
output current (mA)	1500	1000	700	550

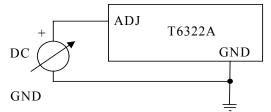
The above values assume that the ADJ pin is floating and at a nominal voltage of VREF (=1.25V).

Note that RS = 0.0660hm is the minimum allowed value of sense resistor under these conditions to maintain switch current below the specified maximum value.

It is possible to use different values of Rs if the ADJ pin is driven from an external voltage. (See next section)

#### Output current adjustment by external DC control voltage

The ADJ pin can be driven by an external dc voltage (VADJ), as shown, to adjust the output current to a value above or below the nominal average value defined by Rs.

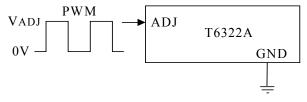


The nominal average output current in this case is given by: IOUTdc = (VADJ /1.25) x (0.1V / RS), [for 0 < VADJ < 2.5V]

Note that 100% brightness setting corresponds to VADJ = VREF. When driving the ADJ pin above 1.25V, RS must be increased in proportion to prevent IOUTdc exceeding 1.5A maximum. The input impedance of the ADJ pin is 200kohm  $\pm 25\%$ .

#### Output current adjustment by PWM control **Directly driving ADJ input**

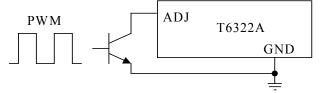
A Pulse Width Modulated (PWM) signal with duty cycle DPWM can be applied to the ADJ pin, as shown below, to adjust the output current to a value above or below the nominal average value set by resistor RS:



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#### Driving the ADJ input via open collector transistor

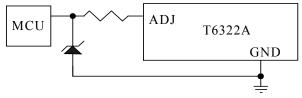
The recommended method of driving the ADJ pin and controlling the amplitude of the PWM waveform is to use a small NPN switching transistor as shown below:



This scheme uses the 200k resistor between the ADJ pin and the internal voltage reference as a pull-up resistor for the external transistor.

#### Driving the ADJ input from a microcontroller

Another possibility is to drive the device from the open drain output of a microcontroller. The diagram below shows one method of doing this:



If the NMOS transistor within the microcontroller has high Drain / Source capacitance, this arrangement can inject a negative spike into ADJ input of the T6322A and cause erratic operation but the addition of a Schottky clamp diode (cathode to ADJ) to ground and inclusion of a series resistor (10K) will prevent this. See the section on PWM dimming for more details of the various modes of control using high frequency and low frequency PWM signals.

#### Shutdown mode

Taking the EN pin to a voltage below 0.8V for more than approximately 100us, will turn off the output and supply current will fall to a low standby level of 35uA nominal.

#### **Capacitor selection**

A low ESR capacitor should be used for input decoupling, as the ESR of this capacitor appears in series with the supply source impedance and lowers overall efficiency. This capacitor has to supply the relatively high peak current to the coil and smooth the current ripple on the input supply. A minimum value of 47uF is acceptable if the input source is close to the device, but higher values will improve performance at lower input voltages, especially when the source impedance is high. In order to avoid high frequency noise influence and improve circuit stability, it is recommended to shunt a value of 0.22uF Capacitor. The input capacitor should be placed as close as possible to the IC. For maximum stability over temperature and voltage, capacitors with X7R, X5R, or better dielectric are recommended. Capacitors with Y5V dielectric are not suitable for decoupling in this application and should not be used.

#### Inductor selection

Recommended inductor values for the T6322A are in the range 33uH to 100uH. Higher values of inductance are recommended at higher supply voltages in order to minimize errors due to switching delays, which result in increased ripple and lower efficiency. Higher values of inductance also result in a smaller change in output current over the supply voltage range. The inductor should be mounted as close to the device as possible with low resistance connections to the LX and VIN pins. The chosen coil should have a saturation current higher than the peak output current and a continuous current rating above the required mean output current.

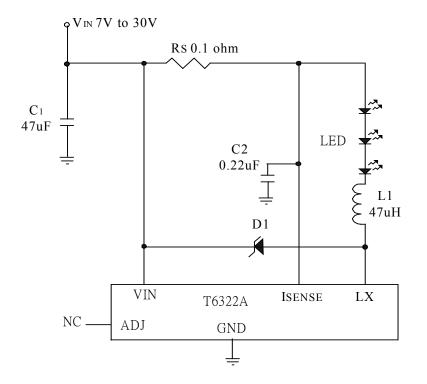
The inductor value should be chosen to maintain operating duty cycle and switch 'on'/'off' times within the specified limits over the supply voltage and load current range.

LX switch on time : ton =  $L\Delta I / (VIN - VLED - Iavg (RS+rL+RLX))$ , note: tonmin > 240ns LX switch off time : toff =  $L\Delta I / (VLED + VD + Iavg (RS+rL))$ , note: toffmin > 200ns

Where:

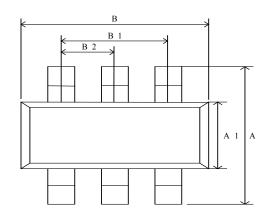
"L" is the coil inductance (H)
"\[]\] "\[]\] Internally set to 0.3 x Iavg}
"rL" is the coil peak-peak ripple current (A) {Internally set to 0.3 x Iavg}
"rL" is the coil resistance (ohm)
"RS" is the current sense resistance
"Iavg" is the required LED current (A)
"VIN" is the supply voltage (V)
"VLED" is the total LED forward voltage (V)
"RLX" is the switch resistance (ohm) {=0.3 ohm nominal}
"VD" is the diode forward voltage at the required load current (V)

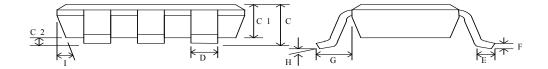
# **TYPICAL APPLICATION CIRCUITS**



T6322A

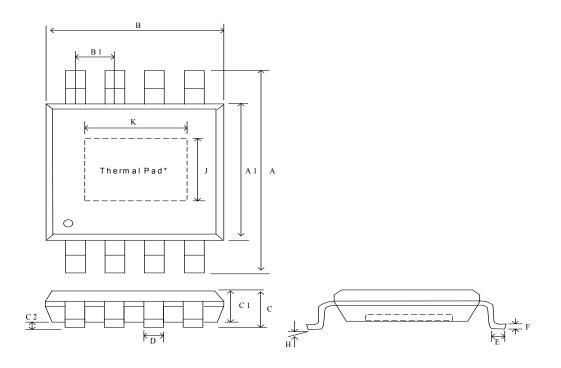
PACKAGE DIMENSIONS SOT-23-6





Symbol	Dimension in mm			Di	Dimension in inch			
Symbol	Min.	Тур.	Max.	Min.	Min. Typ.			
Α	2.60	2.80	3.00	0.102	0.110	0.118		
A1	1.40	1.575	1.60	0.055	0.062	0.063		
В	2.70	2.85	3.00	0.106	0.112	0.118		
B1		1.90(BSC)			0.075(BSC)			
B2		0.95(BSC)			0.037(BSC)			
С	0.95	1.20	1.45	0.037	0.047	0.057		
C1	0.90	1.10	1.30	0.035	0.043	0.051		
C2	0	0.075	0.150	0	0.003	0.06		
D		0.40			0.015			
Е	0.30	0.45	0.60	0.012	0.018	0.023		
F	0.08	0.15	0.22	0.003	0.006	0.009		
G		0.60(REF)						
Н				0~8°				
Ι		5~15°		5~15°				

# PACKAGE DIMENSIONS 8-LEAD SOP



Symbol	Ι	Dimension in n	ım	D	imension in inc	h
Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.
А	5.70	6.00	6.30	0.224	0.236	0.248
A1	3.75	3.95	4.10	0.148	0.156	0.164
В	-	-	5.13	-	-	0.202
B1	-	1.27	-	-	0.050	-
С	-	-	1.80	-	-	0.071
C1	1.35	1.55	1.75	0.052	0.061	0.069
C2	0.10	-	0.25	0.001	-	0.004
D	0.31	0.41	0.51	0.012	0.016	0.020
Е	0.30	0.50	0.70	0.012	0.020	0.028
F	0.10	0.15	0.25	0.004	0.006	0.010
J		2.23 REF			0.088 REF	
K		2.97 REF			0.117 REF	
Н		0~8°			0~8°	

#### \*Note :

The thermal pad on the IC's bottom has to be mounted on the copper foil.

To eliminate the noise influence, the thermal pad is suggested to be connected to GND on PCB. In addition, desired thermal conductivity will be improved, if a heat-conducting copper foil on PCB is soldered with thermal pad. The thermal pad enhances the power dissipation. As a result, a large amount of current can be sunk safely in one package.